

Active

- L9 (3260) (257/377,382,384,388,412,413,486,754)
- L10 (253) 9 and metal near3 silicide with transistor
- L12 (3757) 10 and (((silicon adj nitride) or SiN) with
- L14 (1) 10 and (((silicon adj nitride) or SiN) and met

 Failed

- (0) ((silicon adj nitride) or SiN) with (conformality w

 Saved

- (2384) metal near3 silicide with transistor
- (0) ((silicon adj nitride) or SiN) with (conformality w
- (0) (metal near3 silicide with transistor) and (((silicon
- (32) ((silicon adj nitride) or SiN) with conformality
- (3717) (((silicon adj nitride) or SiN) with conformalit
- (1) (((silicon adj nitride) or SiN) with conformality) a
- (24521) metal near3 silicide
- (10) (metal near3 silicide) and (((silicon adj nitride) o
- (1701) (257/640,649,760,900) CCLS

DBs: USPA1, US-POPOB, EPD, JPO, DERWENT, IBM, TOB
 Plurals
 Default operator: OR
 Highlight all int terms initially

U	I	Document ID	Issue Date	Pages	Title	Current	Cur	Re	Inventor	S	C	P	R	3
1	<input checked="" type="checkbox"/>	US 20030022437 A1	20030130	23	Method of forming integrat	438/245	438/		Fishburn, Fred	<input checked="" type="checkbox"/>				
2	<input checked="" type="checkbox"/>	US 6475855 B1	20021105	22	Method of forming integrat	438/239	438/		Fishburn, Fred	<input checked="" type="checkbox"/>				
3	<input checked="" type="checkbox"/>	US 6740559 B2	20040525	40	Semiconductor device co	438/303	438/		Higuchi, Toshihiko	<input checked="" type="checkbox"/>				
4	<input checked="" type="checkbox"/>	US 6461951 B1	20021108	9	Method of forming a side	438/592	257/		Besser, Paul et al.	<input checked="" type="checkbox"/>				
5	<input checked="" type="checkbox"/>	US 6344677 B1	20020205	40	Semiconductor device co	257/408	257/		Higuchi, Toshihiko	<input checked="" type="checkbox"/>				
6	<input checked="" type="checkbox"/>	US 6258646 B1	20010710	11	CMOS integrated circuit	438/231	257/		Fulford, Jr., H. Jim	<input checked="" type="checkbox"/>				
7	<input checked="" type="checkbox"/>	US 6100142 A	20000808	10	Method of fabricating su	438/291	257/		Liao, Kuan-Yang	<input checked="" type="checkbox"/>				
8	<input checked="" type="checkbox"/>	US 6144071 A	20001107	18	Ultrathin silicon nitride c	257/344	257/		Gardner, Mark I. et	<input checked="" type="checkbox"/>				

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